

Graphine on SiO₂, Transport in FHI-aims

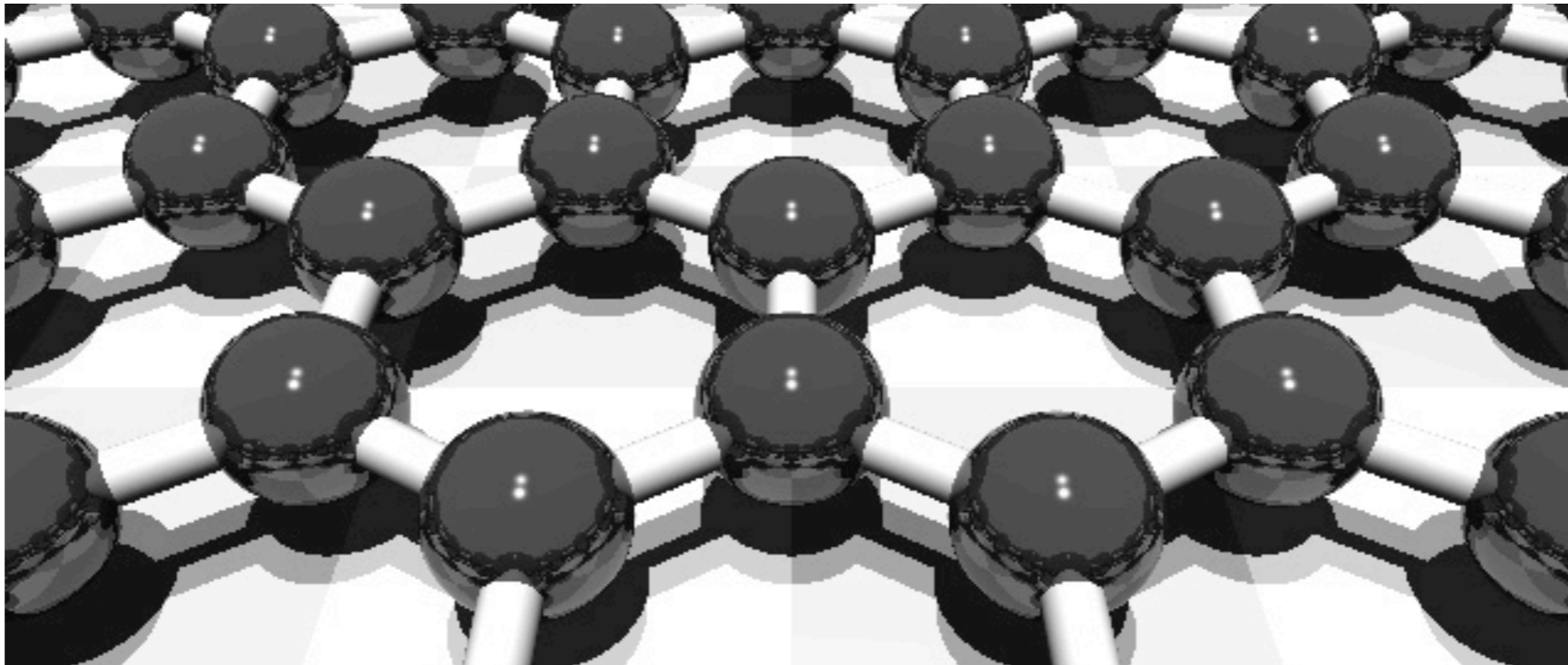
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Aalto University

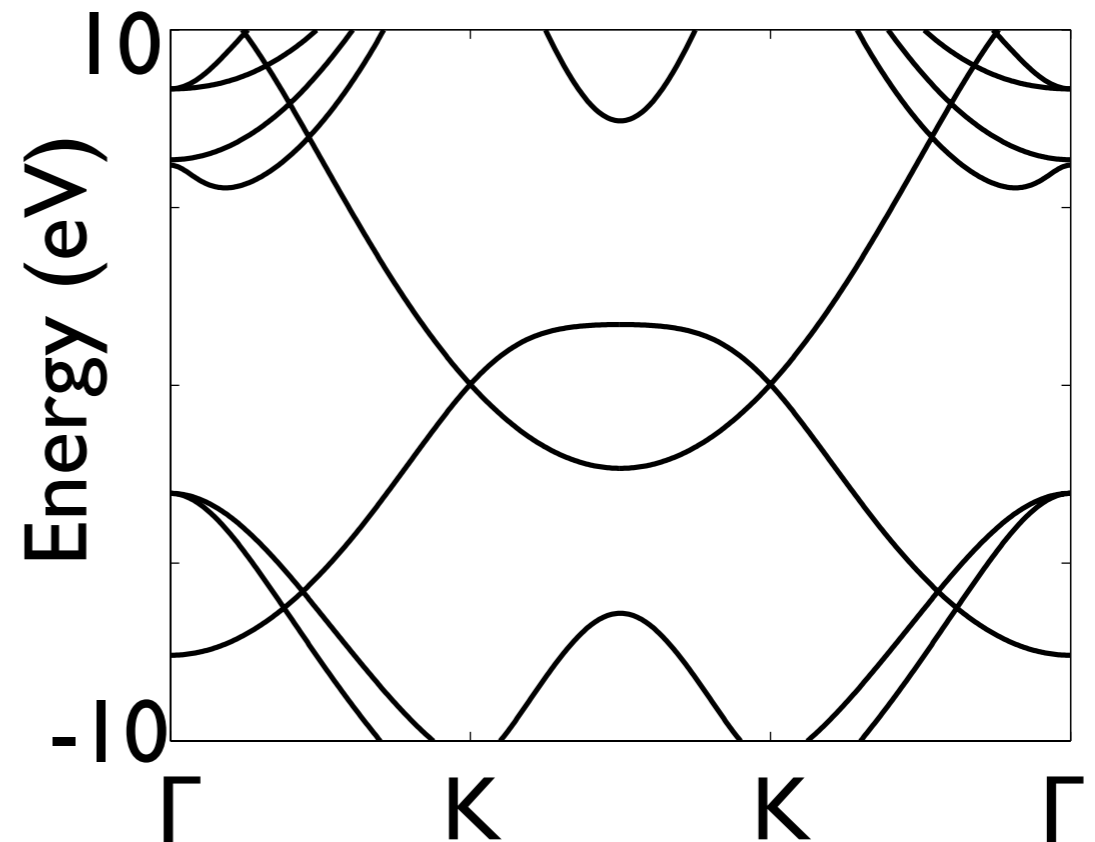
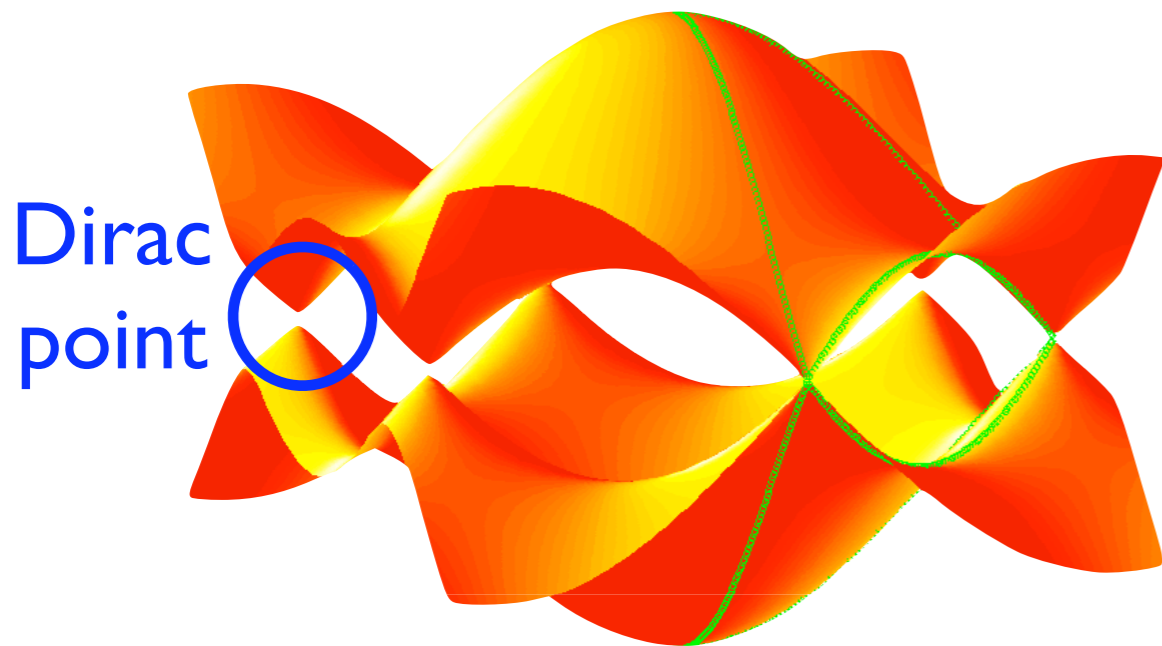
Outline

- Graphene on SiO₂
- Hydrogenated graphene on SiO₂
- Electron transport with FHI-aims

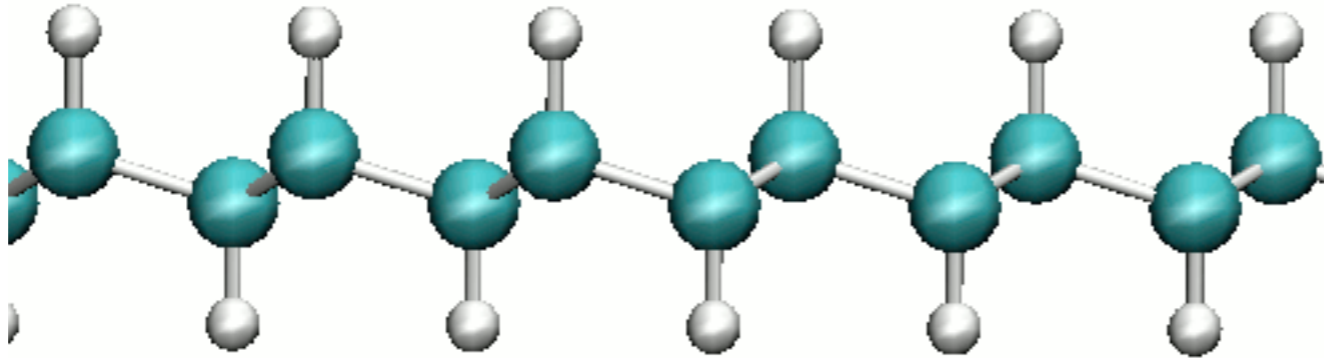


Graphene: 2D Carbon

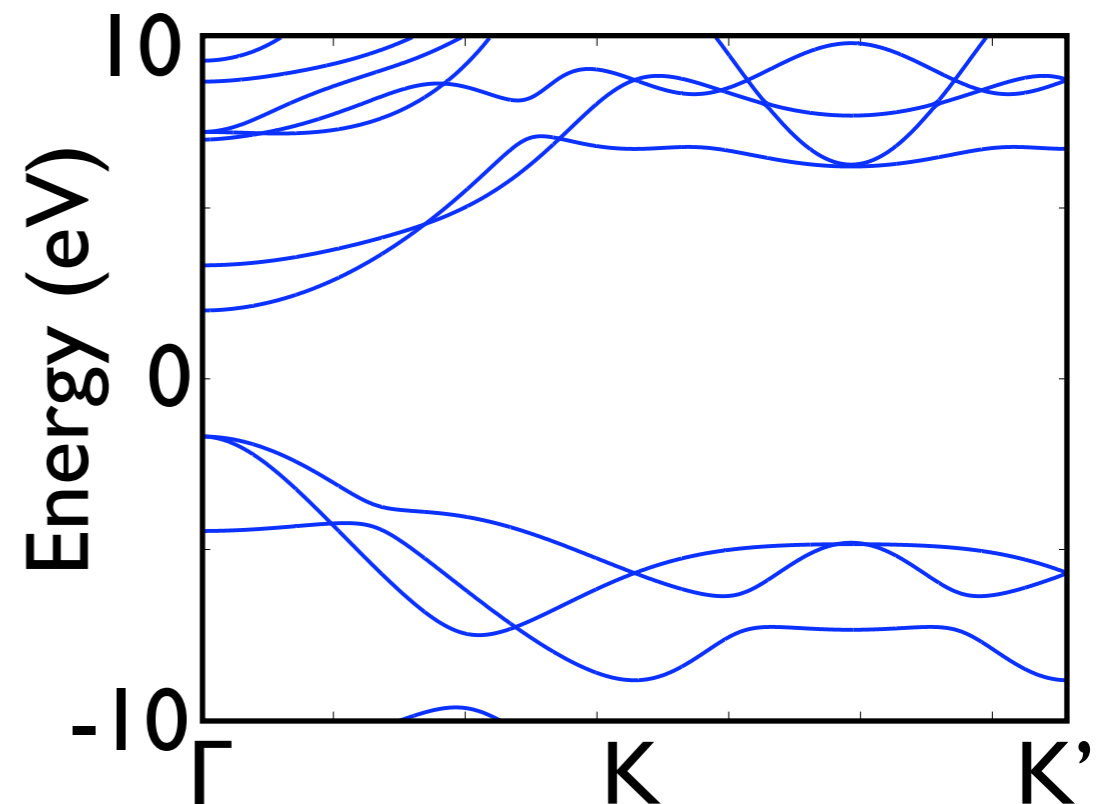
- Perfect semi-metal with linear dispersion
- Carbon atomic configuration $(1s)^2(2s)^2(2p)^2$
- Graphene: sp^2 from 2s and two p-orbitals, p_z remains



Hydrogenated graphene - Graphane



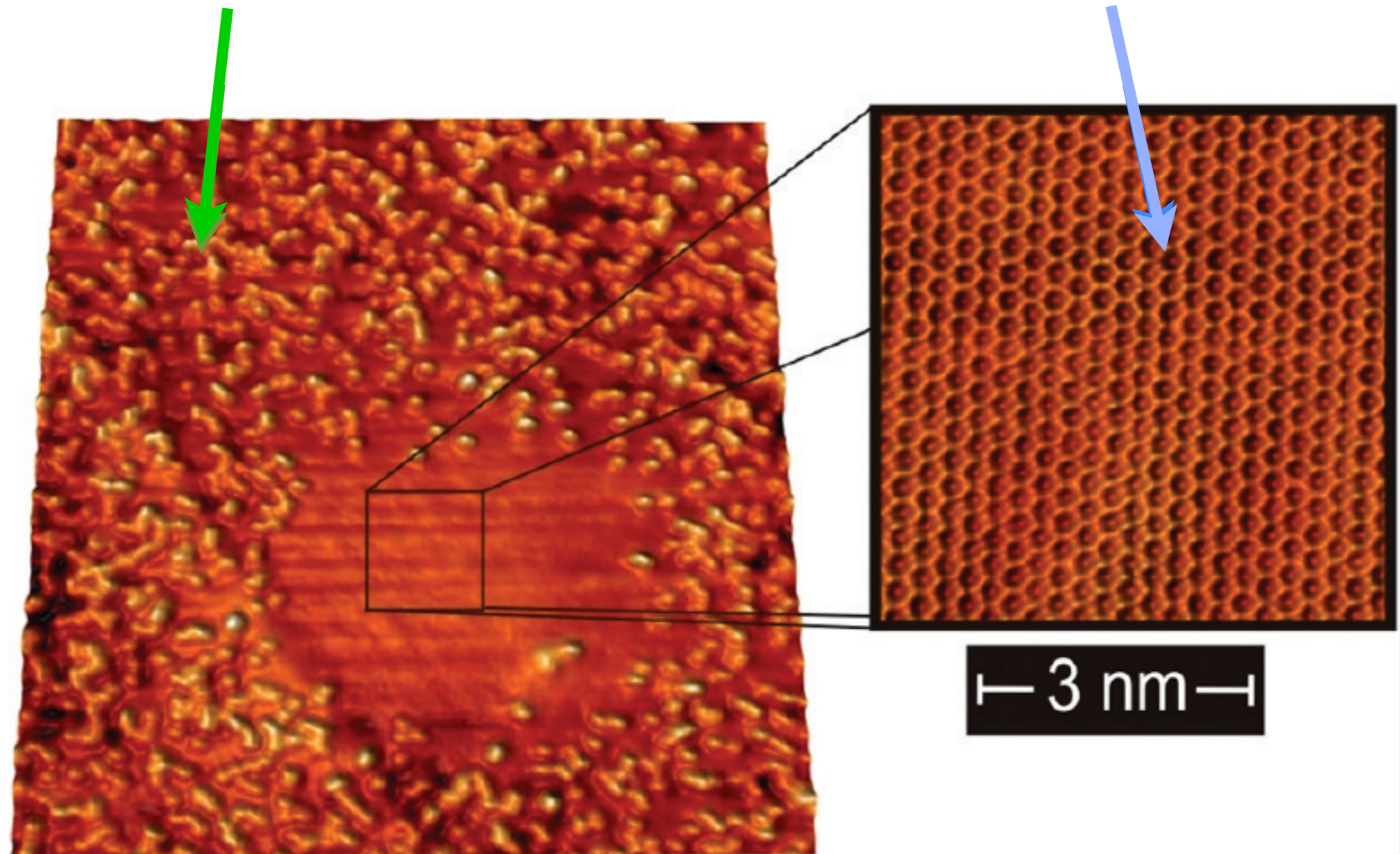
- Free-standing graphene hydrogenated on both sides is stable.
- Free-standing graphene hydrogenated only on single side is not theoretically stable.
- Graphane is an insulator



Hydrogenated graphene in experiments

- Typically placed on surfaces

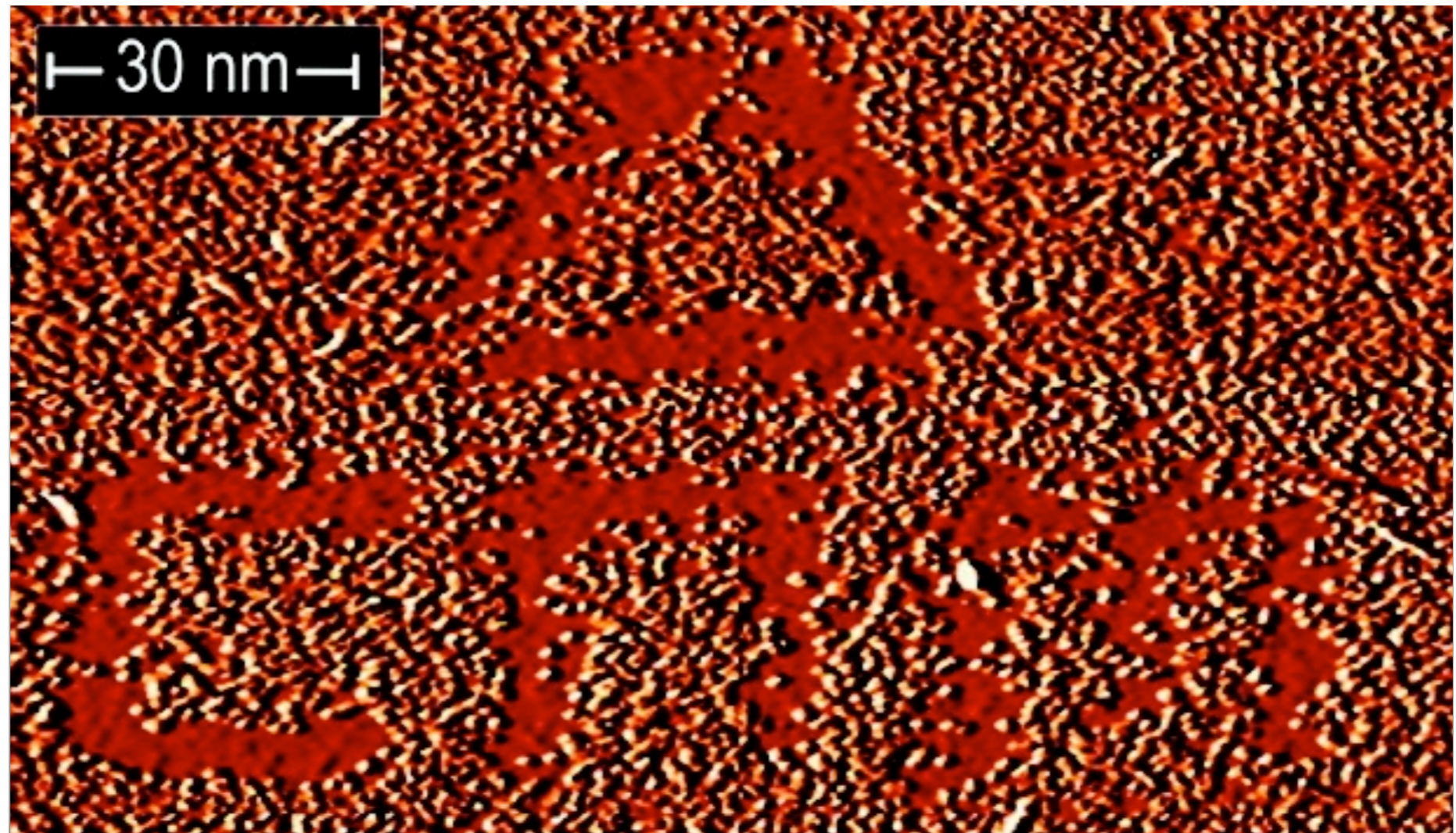
Hydrogenated graphene and hydrogens removed by STM.



Paolo Sessi et al., Nano Lett, **9**, 4343 (2009).

Hydrogenated graphene in experiments

- Writable graphene circuit board?

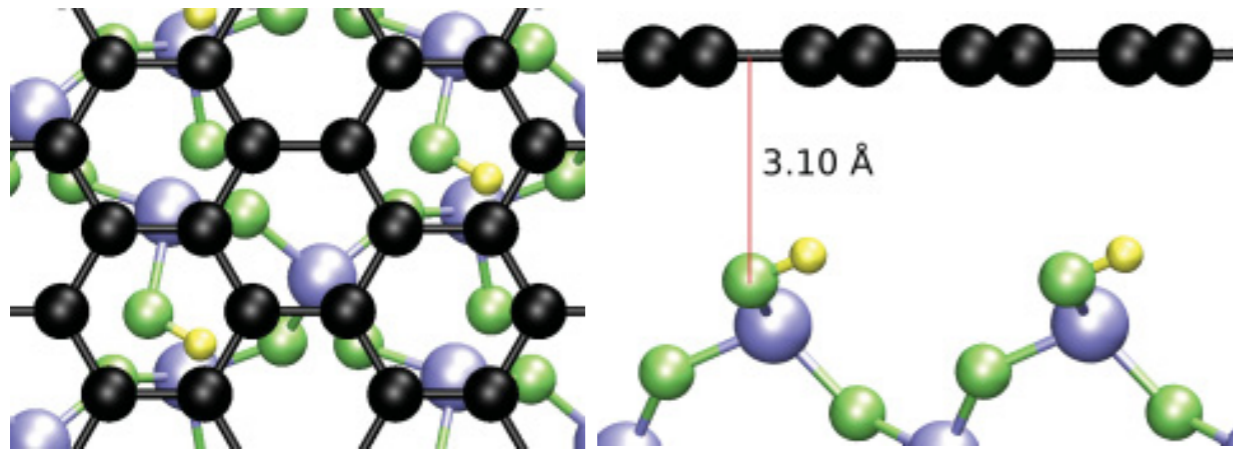


Paolo Sessi et al., Nano Lett, 9, 4343 (2009)

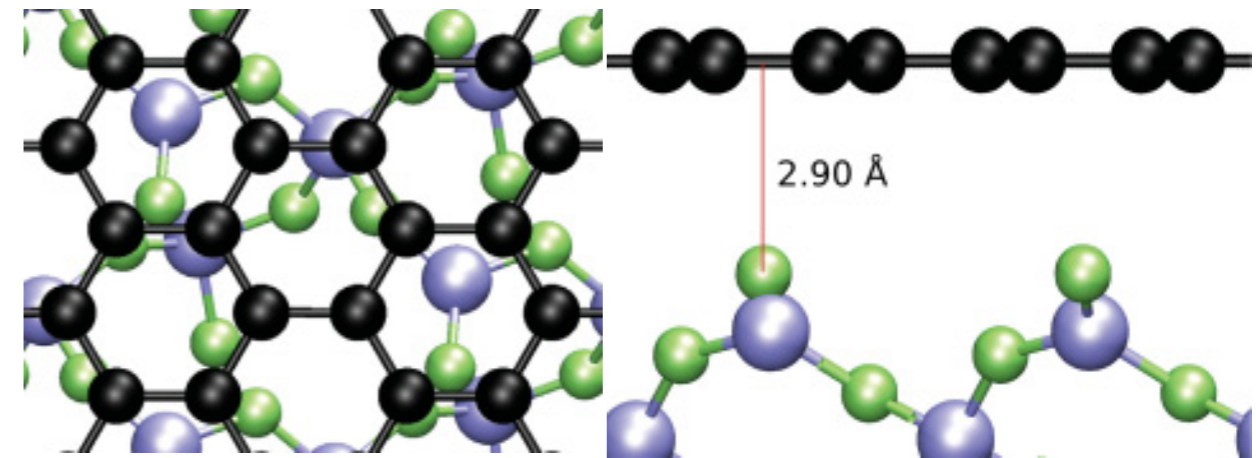
Graphene on SiO₂

- In our study we use 4 different surfaces

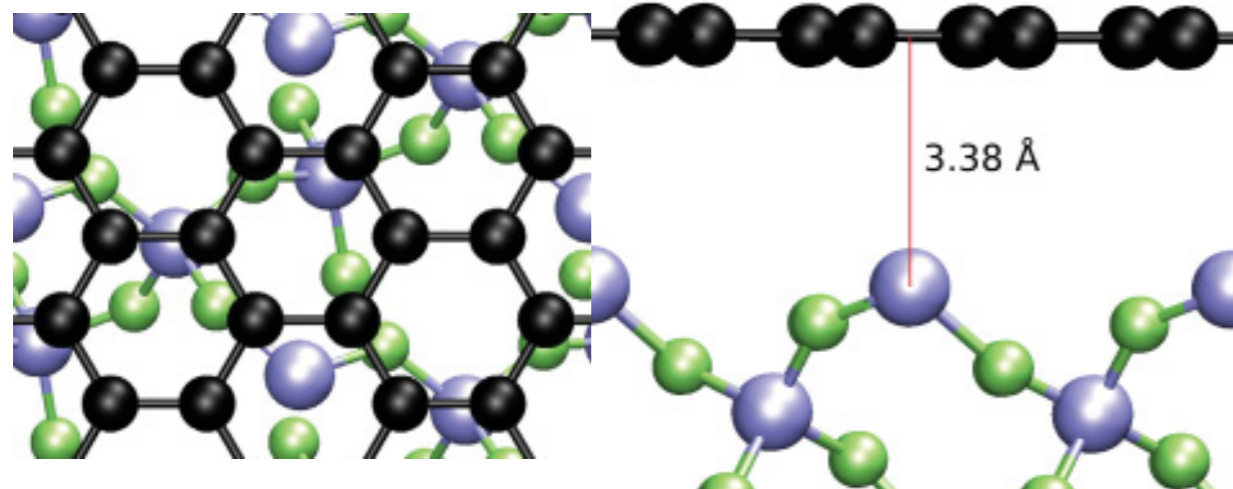
OH Terminated



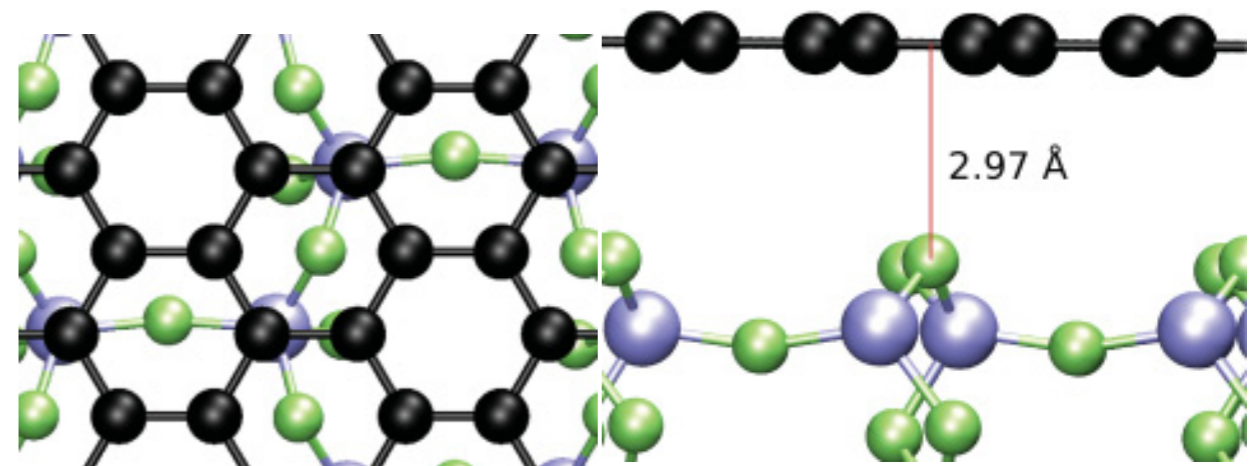
O Terminated



Si Terminated



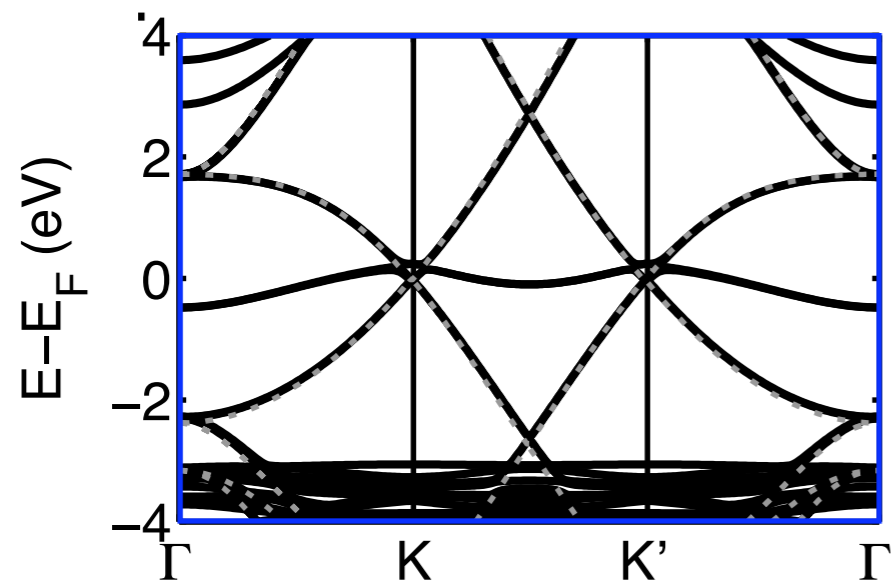
Reconstructed O Terminated



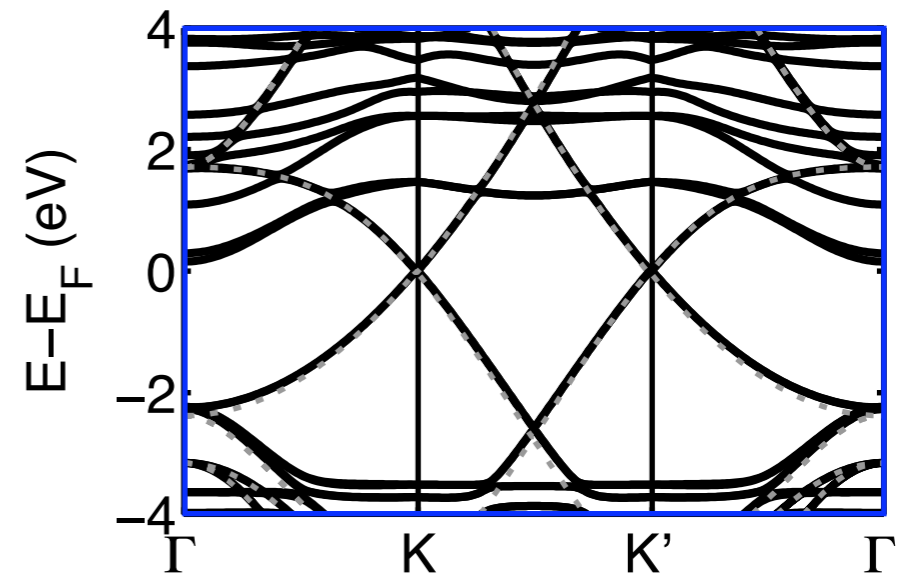
Graphene on SiO2

- Bands are close to isolated graphene

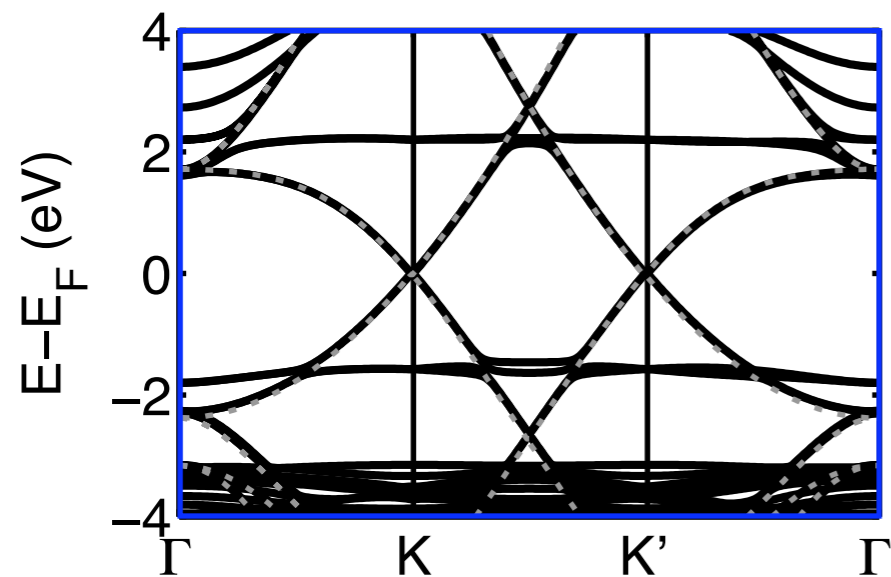
OH Terminated



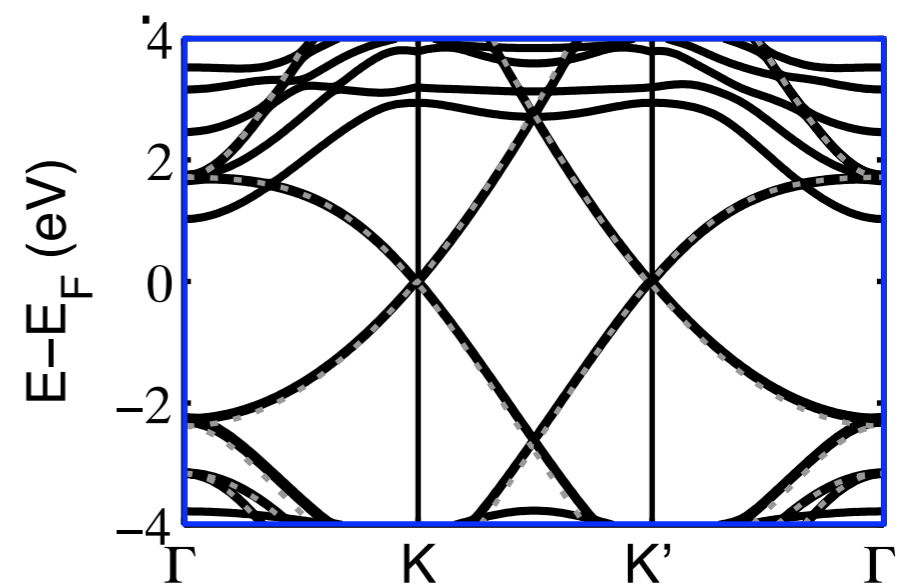
O Terminated



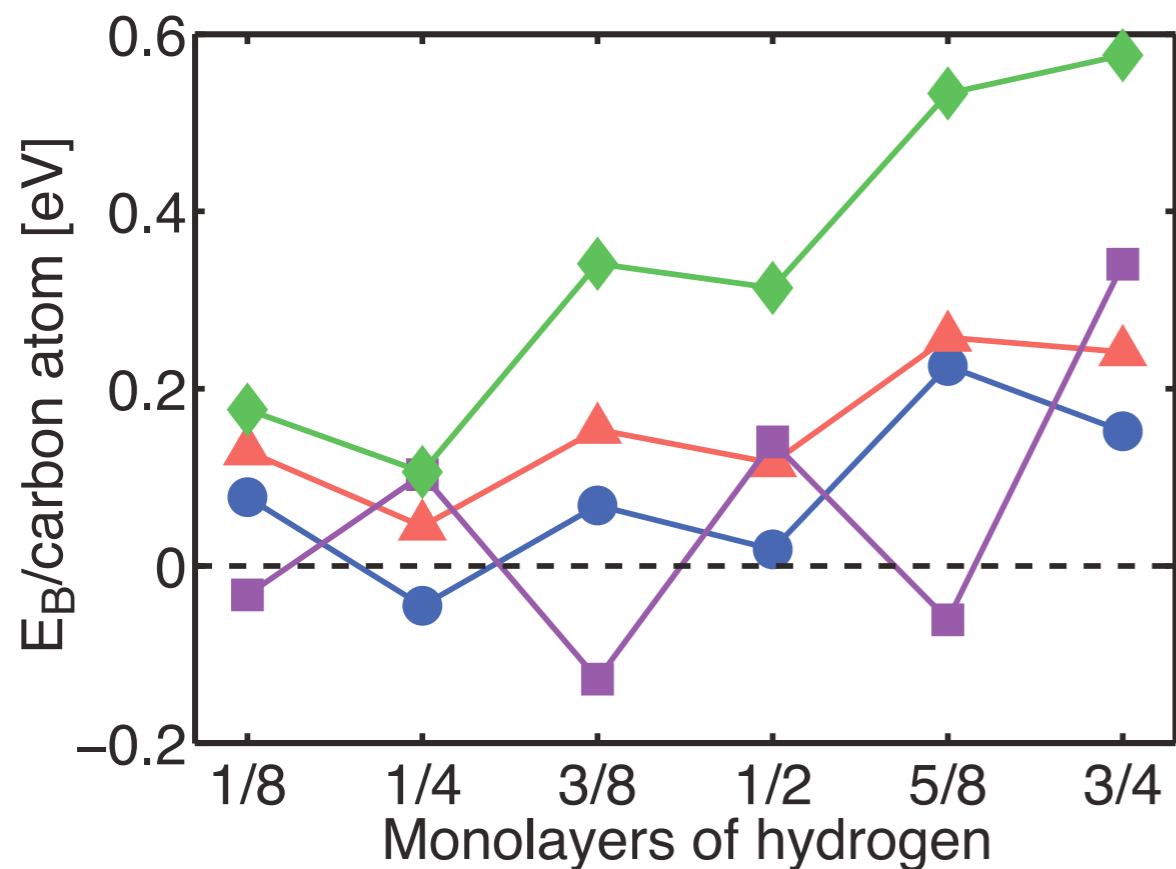
Si Terminated



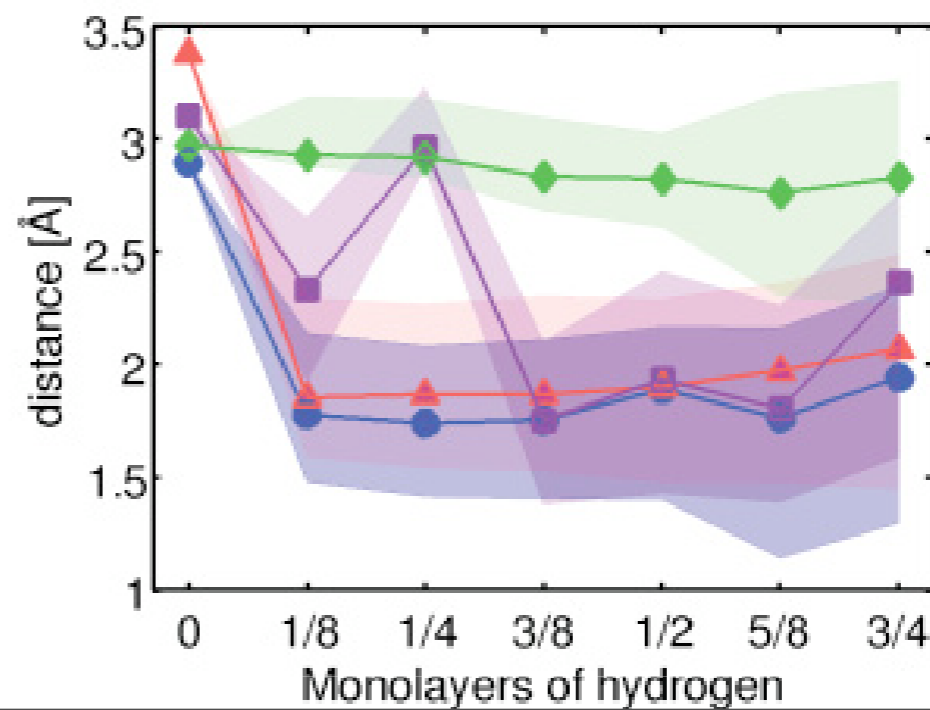
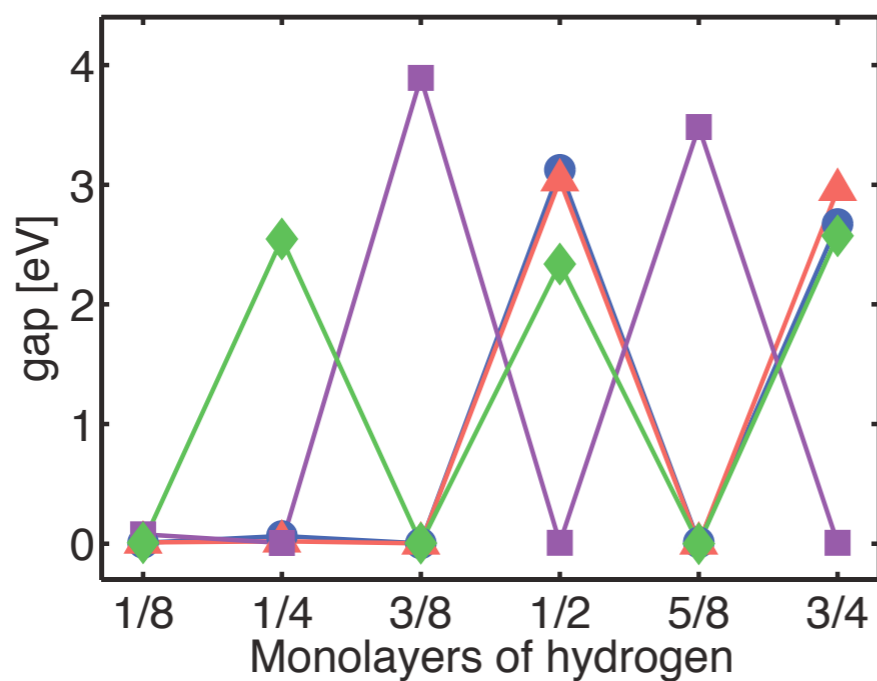
Reconstructed



Graphane on SiO2

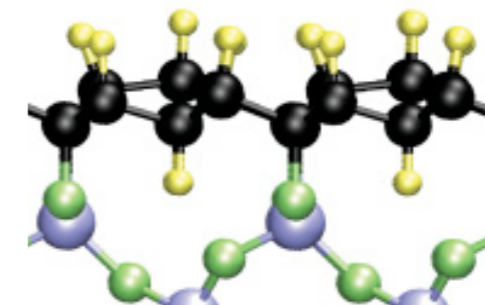
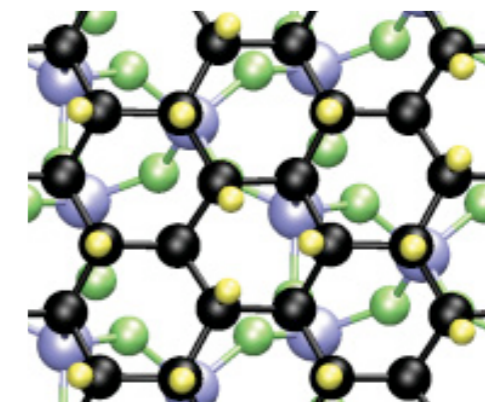
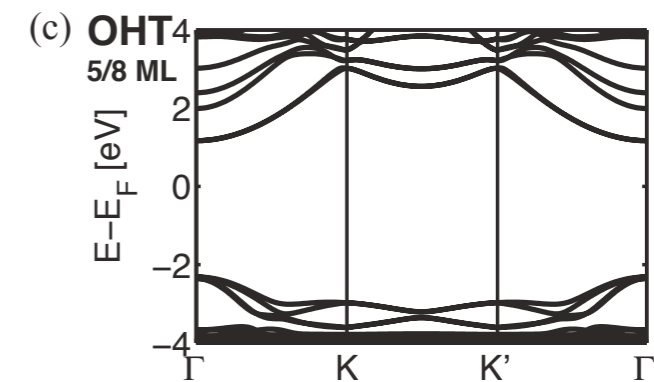
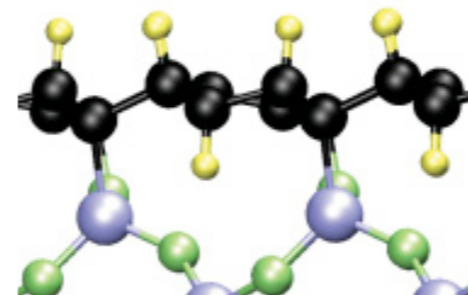
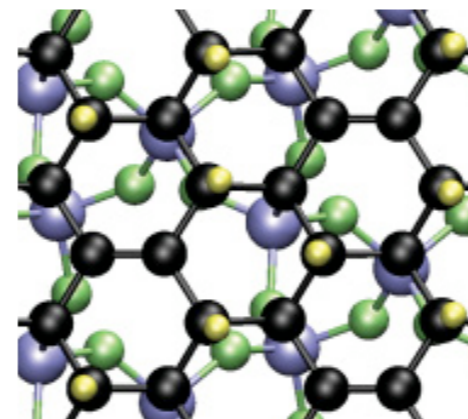
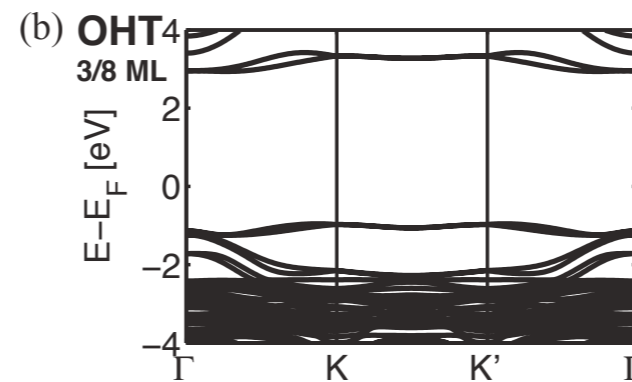
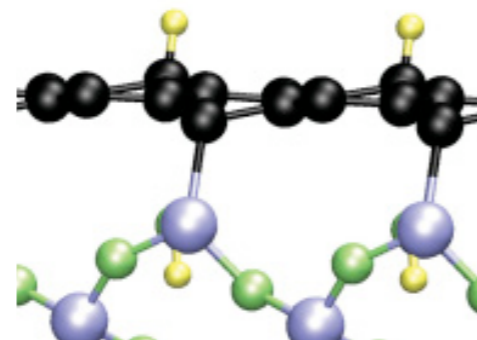
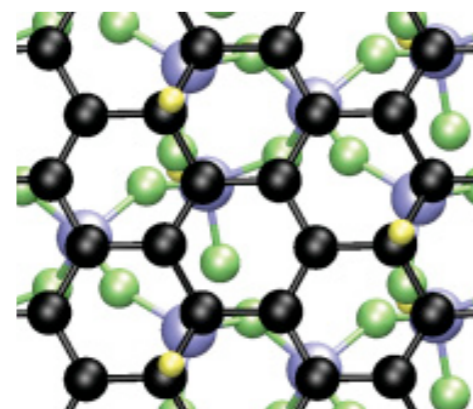
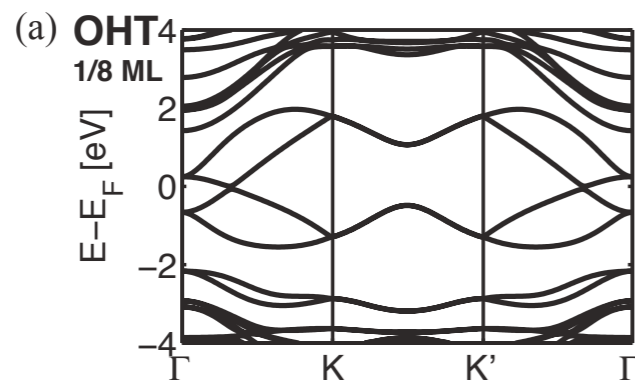
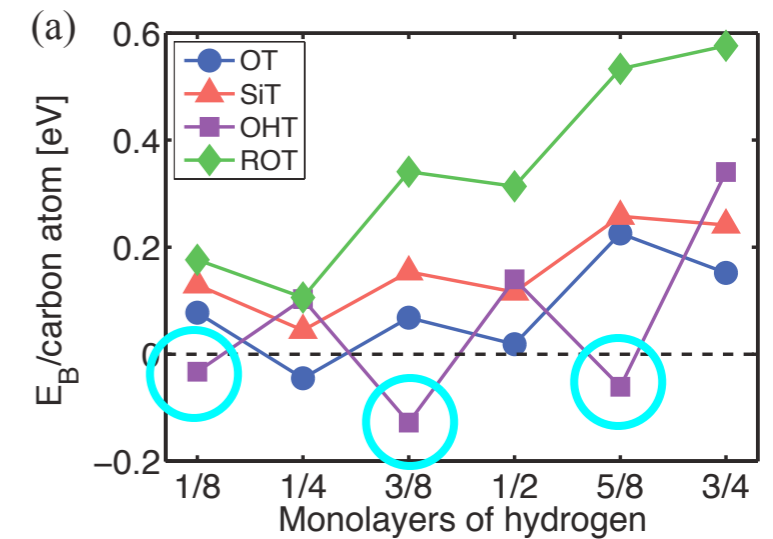


- O terminated
- ▲ Si terminated
- OH terminated
- ◆ Reconstructed



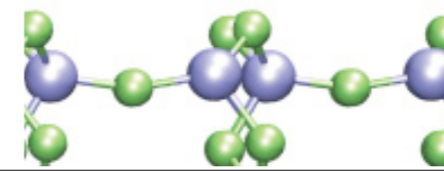
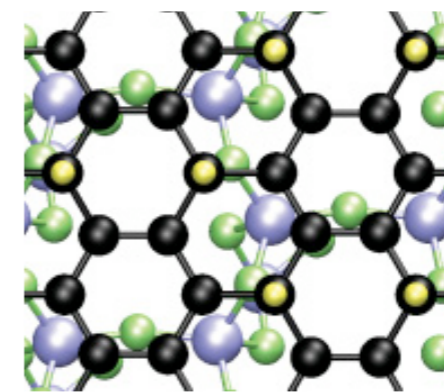
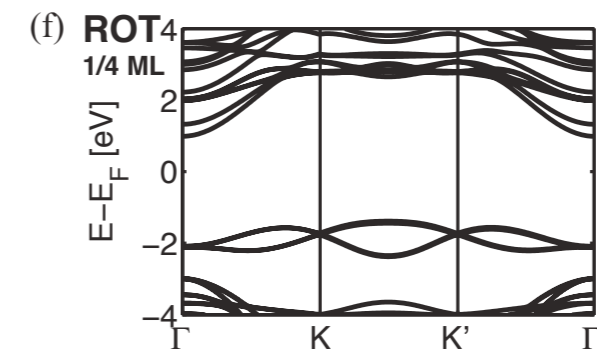
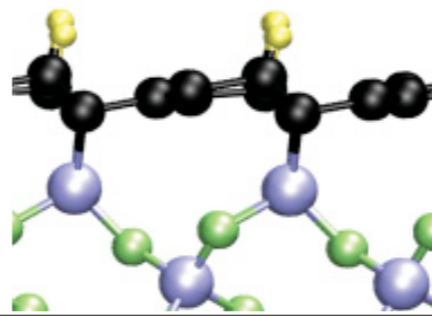
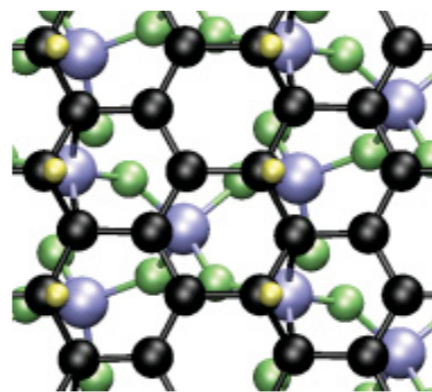
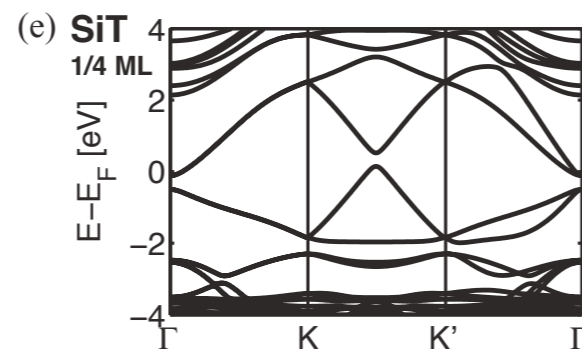
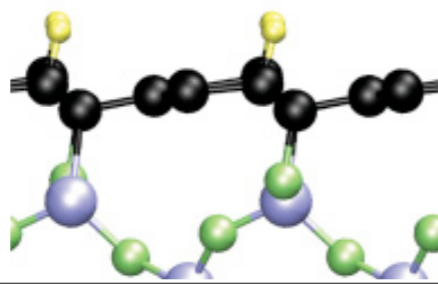
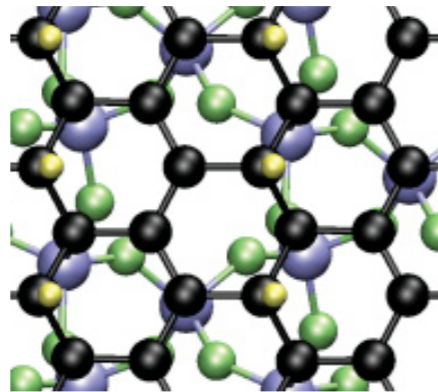
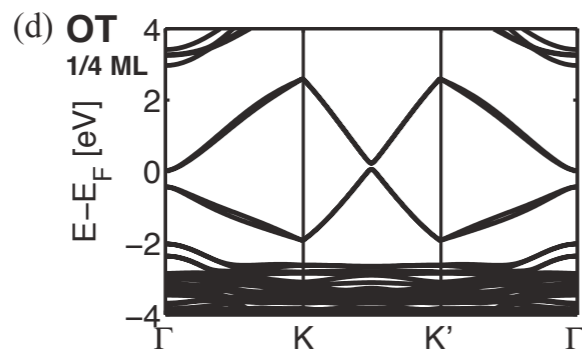
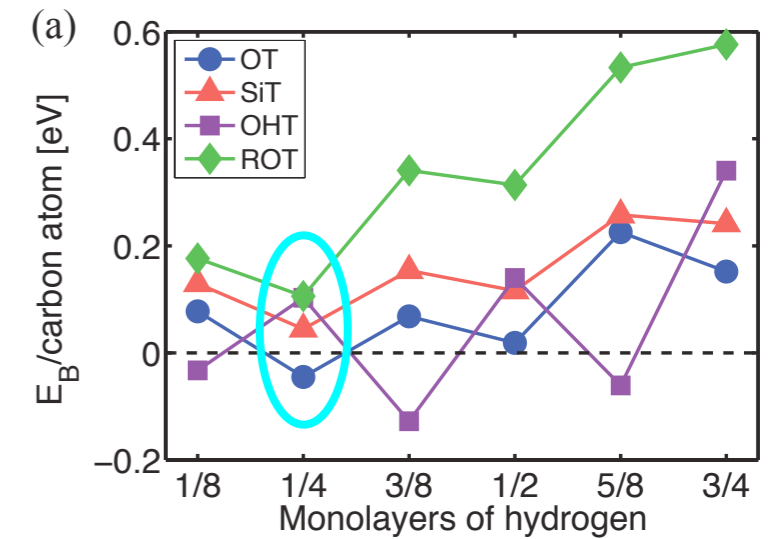
Graphane on SiO₂ - OH terminated surface

- 3 stable geometries with OH terminated surface.



Graphane on SiO2

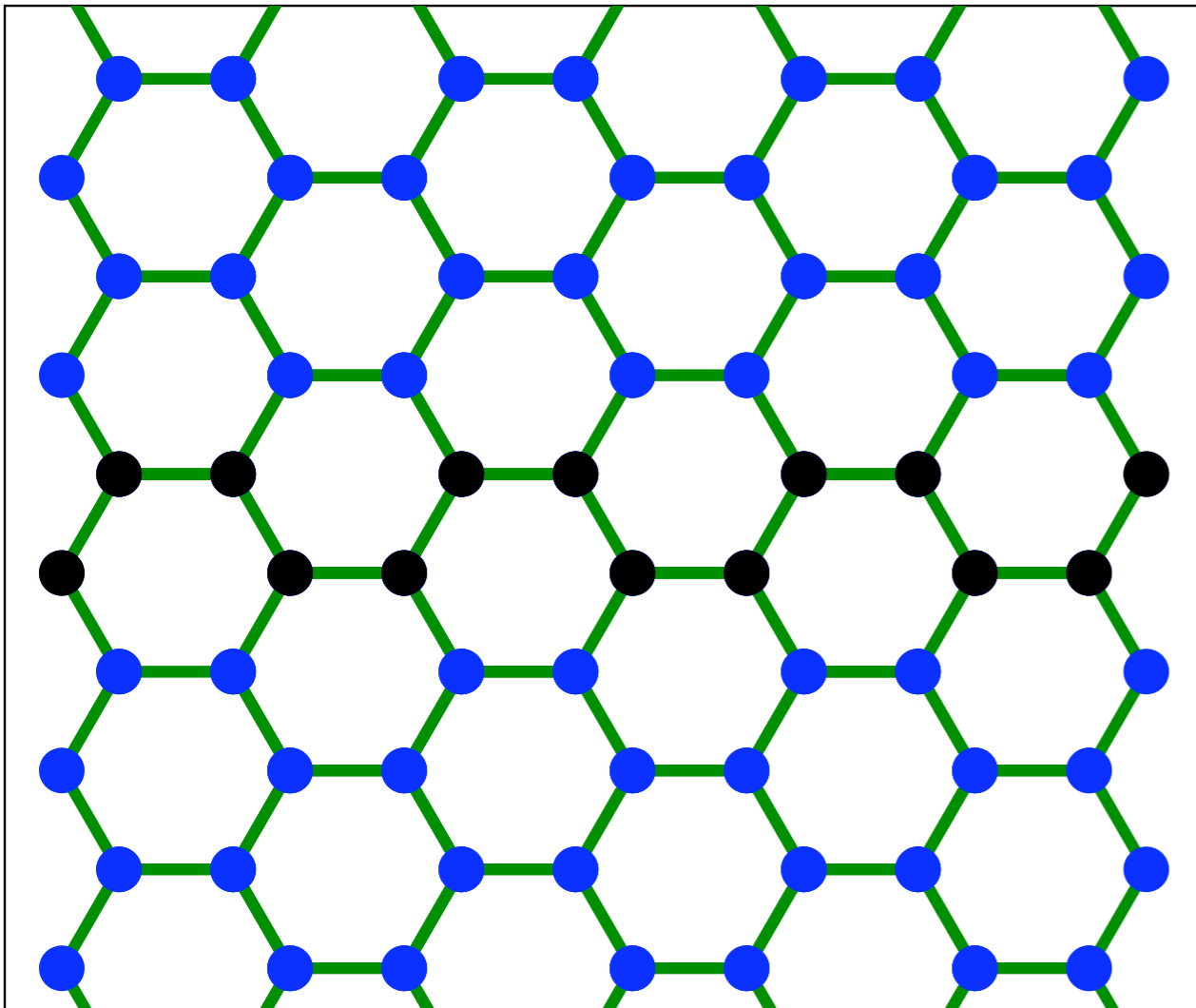
- O, Si and reconstructed surfaces are most stable at 1/4 filling of H.



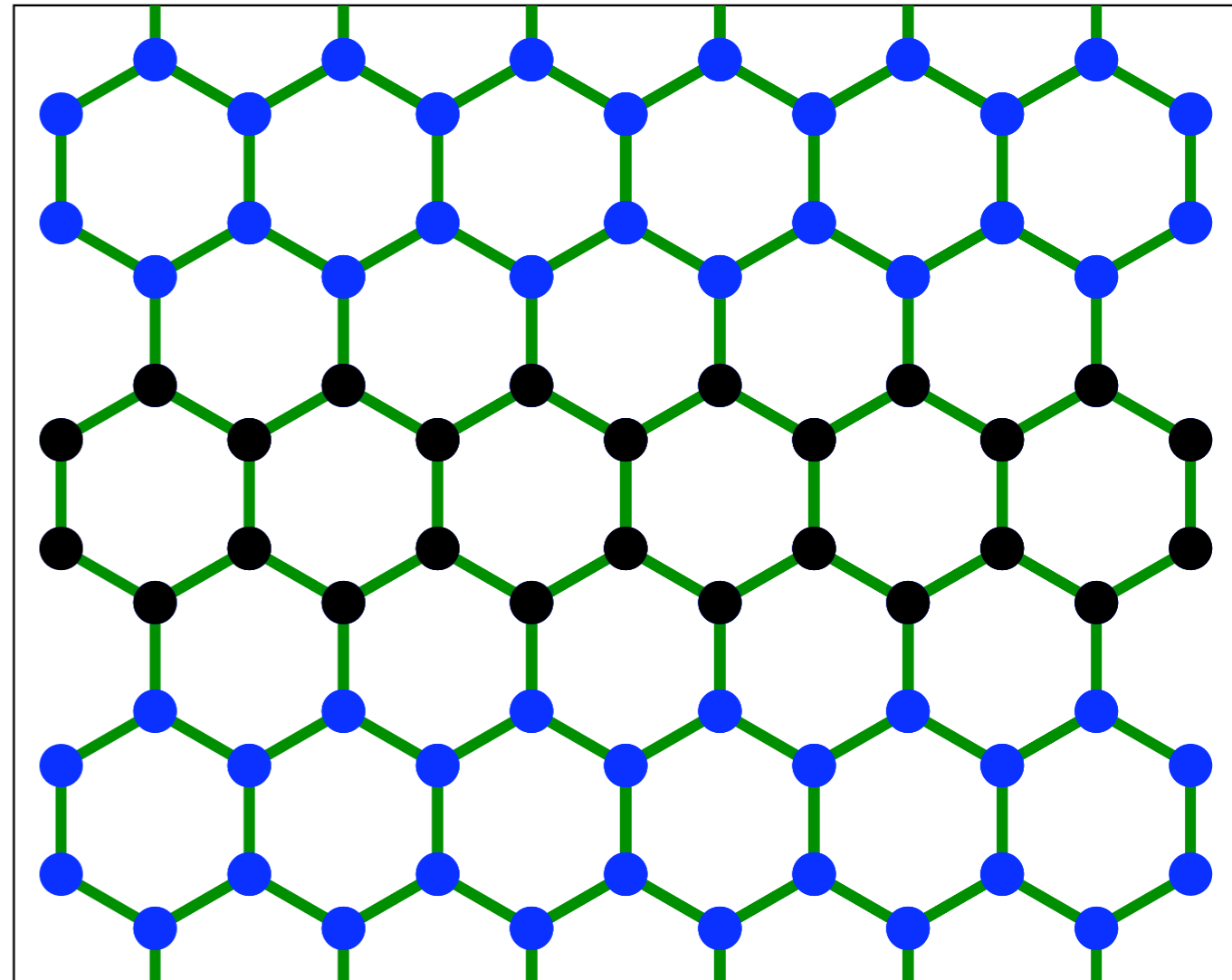
Graphene nanoribbons

Two basic types:

Armchair



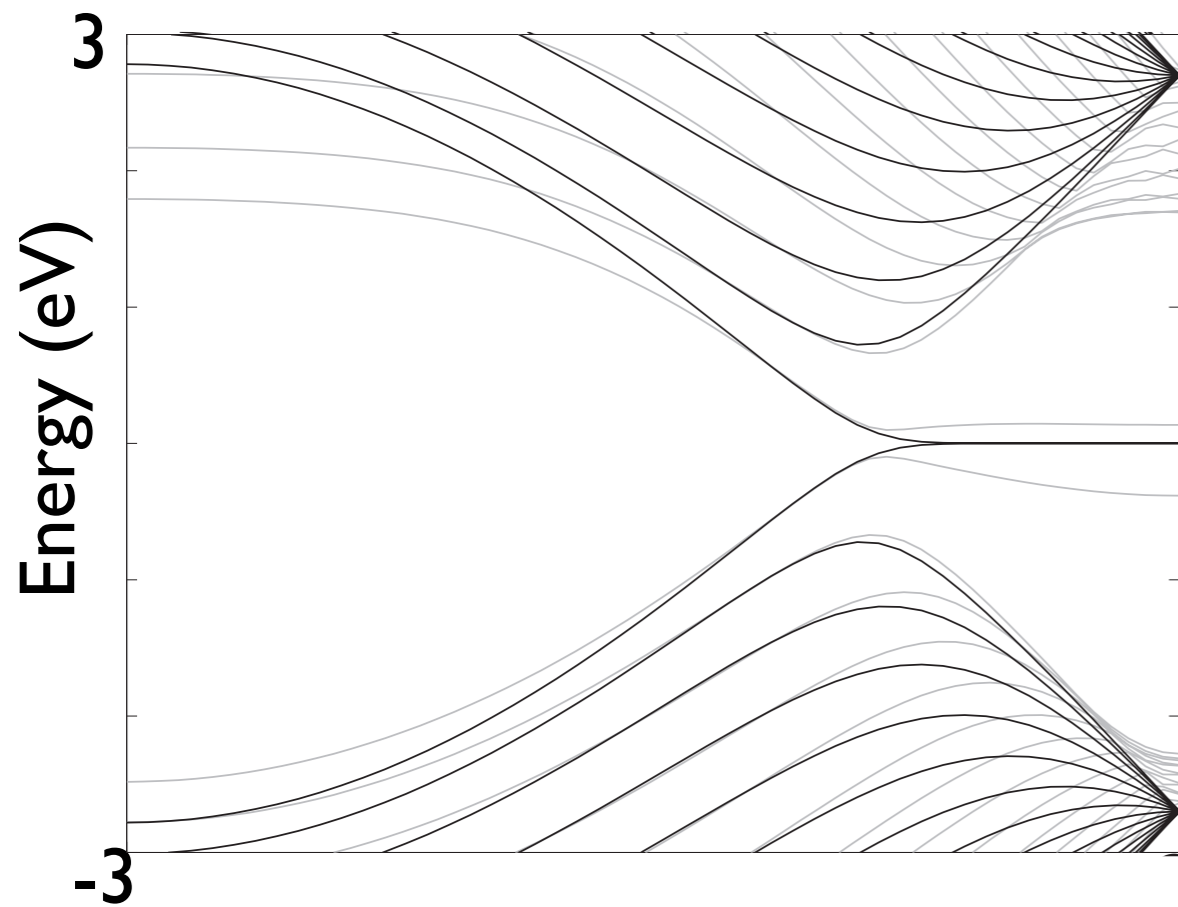
Zigzag



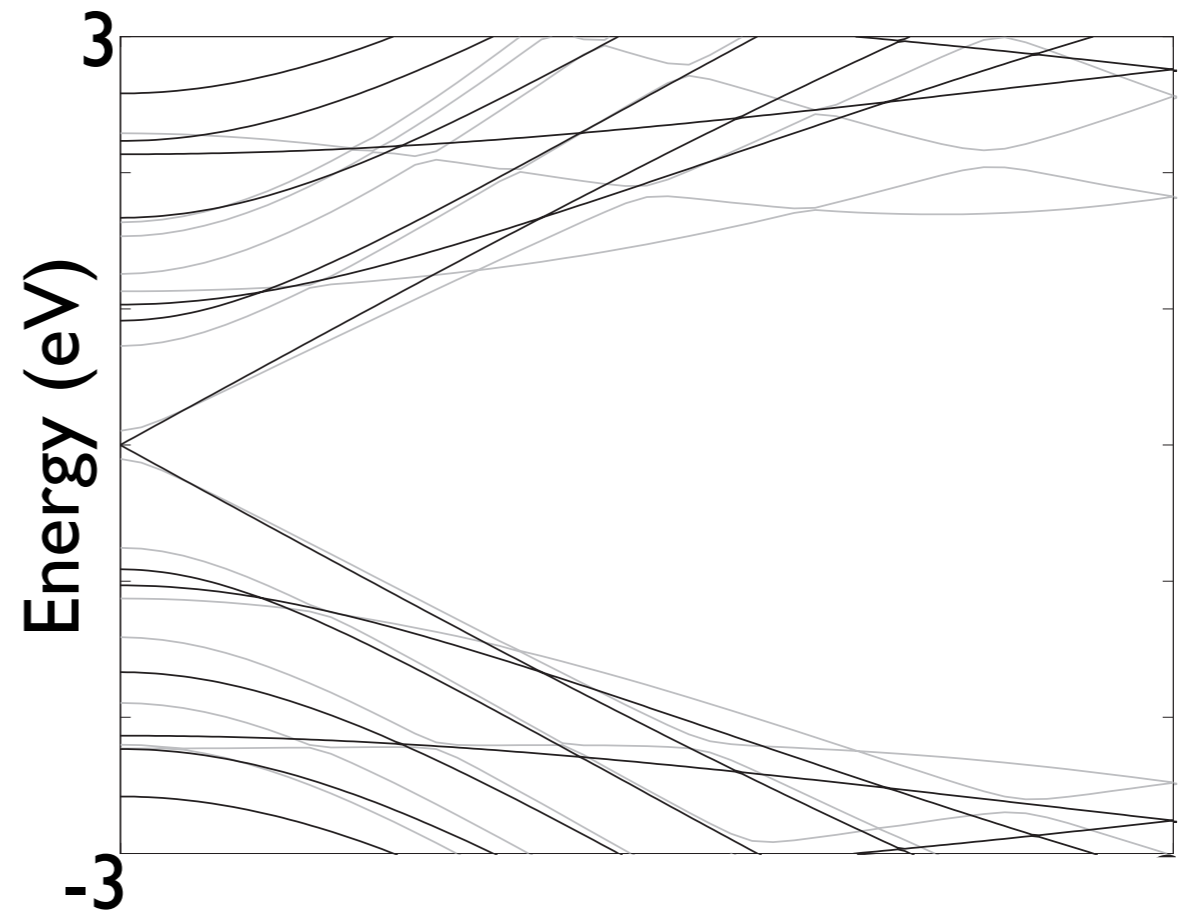
Graphene nanoribbons

Different electronic structures:

Zigzag



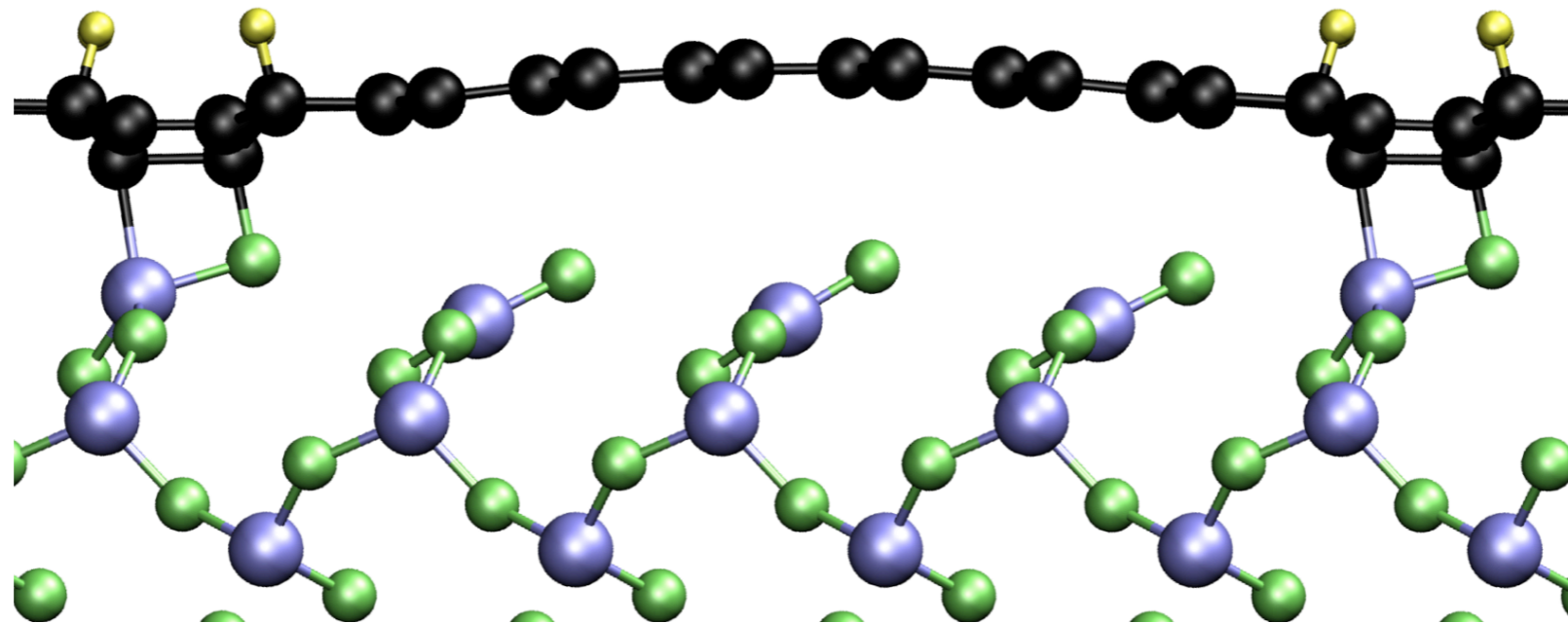
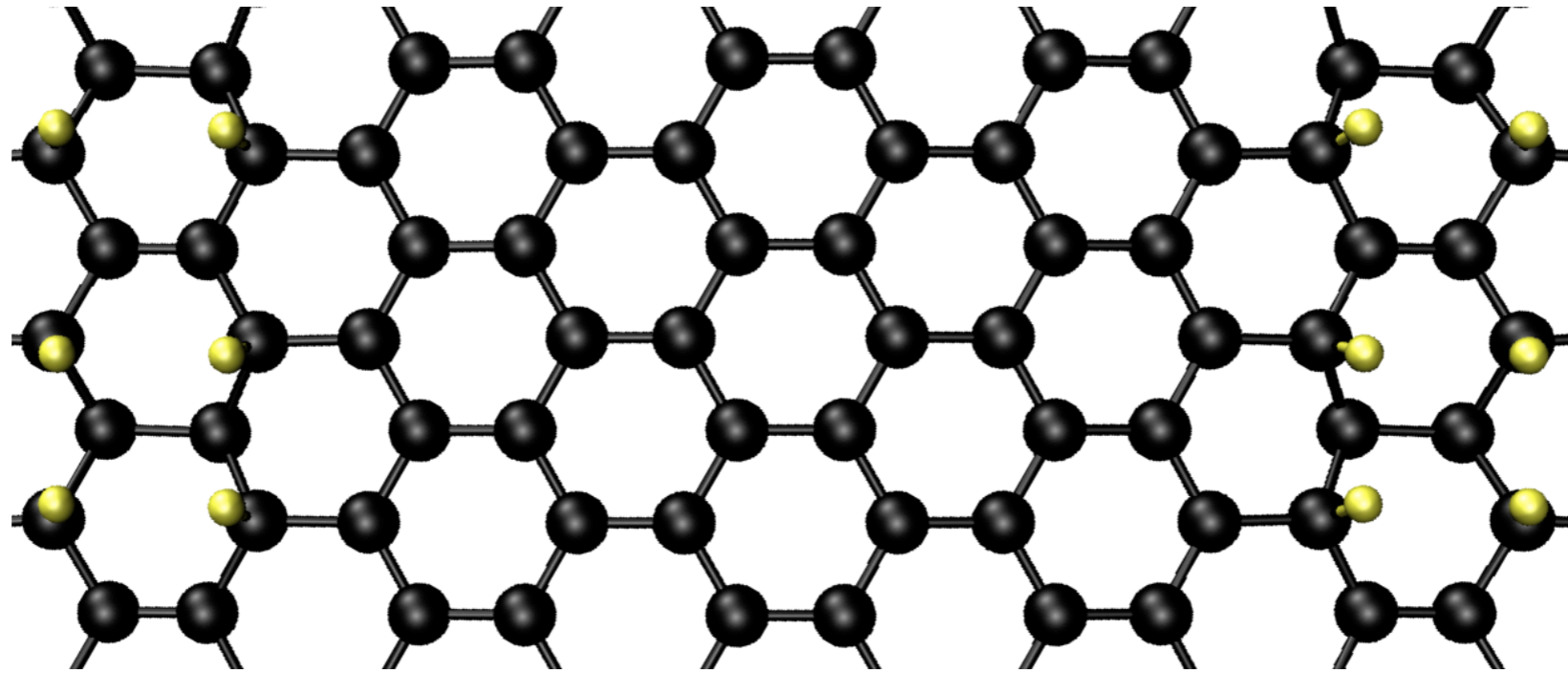
Armchair



Simple Tight-binding and Density-functional theory

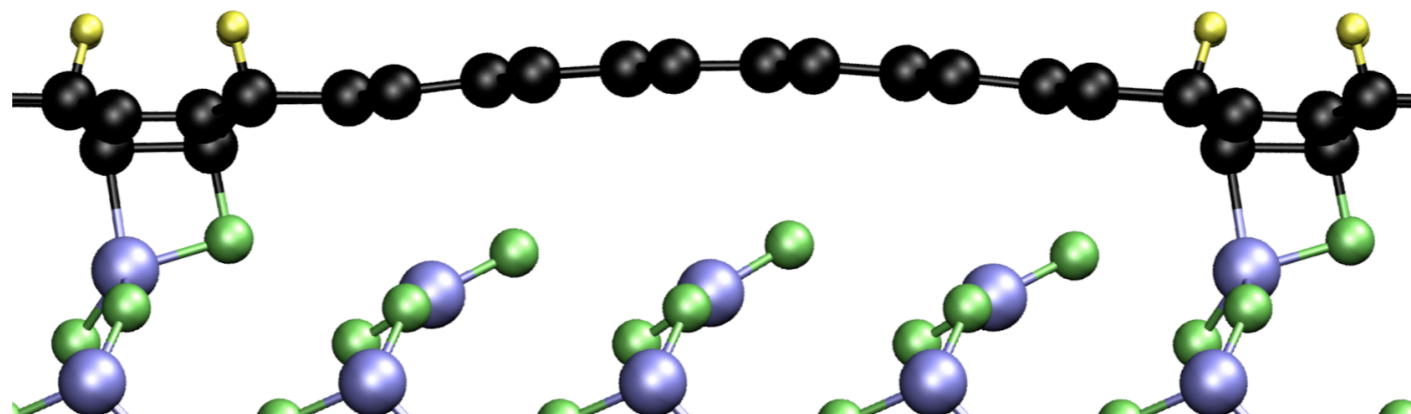
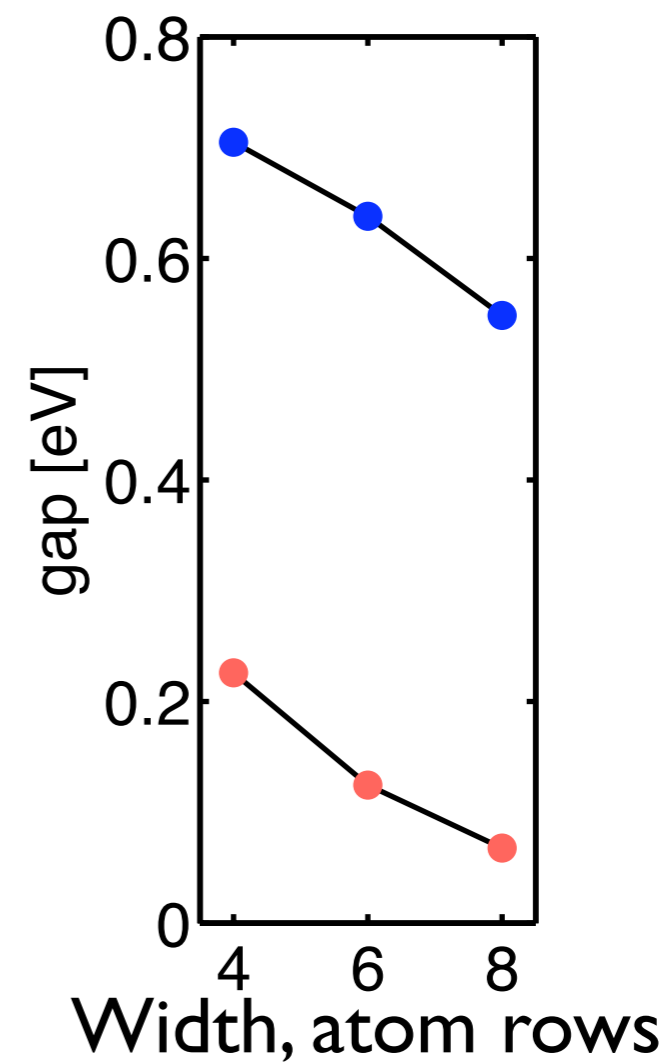
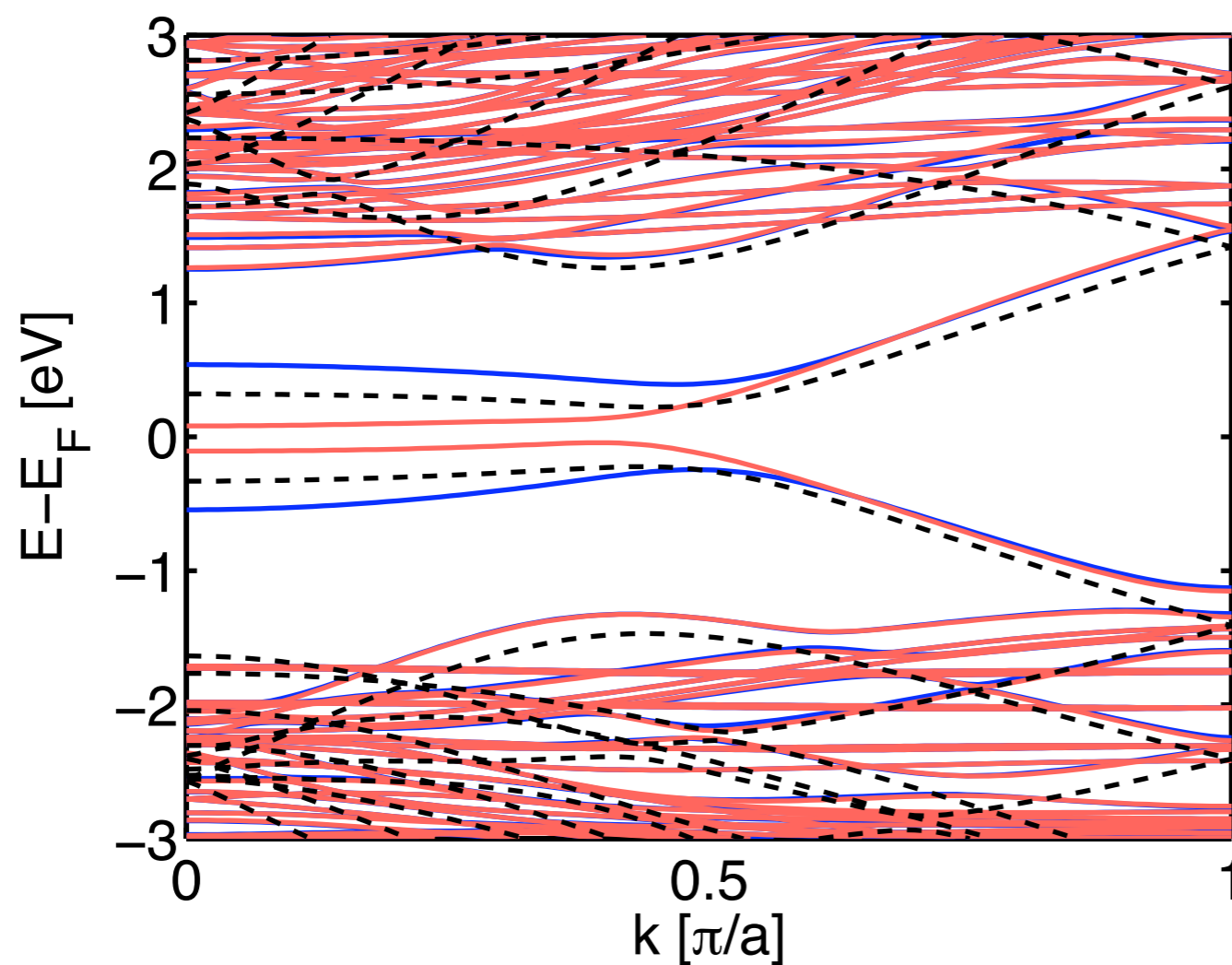
Edge magnetism:
longer range hopping and
interaction needed

Graphane nanoribbons on SiO₂



Electronic structure

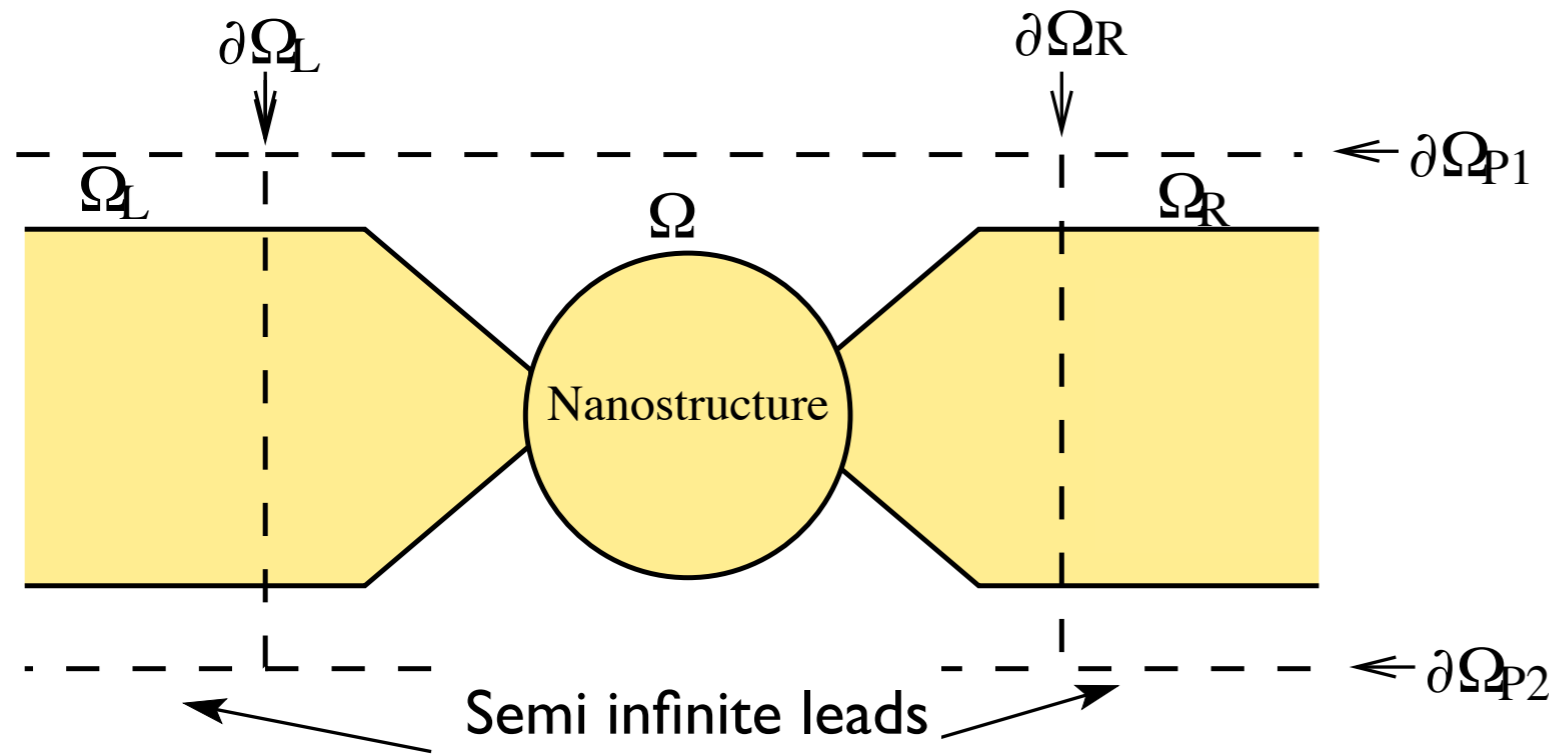
- Spin-dependent bands (**up** and **down**)



Summary of graphene

- The substrate has a big effect on the properties of one side hydrogenated graphene.

Transport in FHI-aims



- Electron tunneling through the nano structure with semi-infinite leads
- Zero-bias transport limit
- Use of gate voltage possible (adding or removing electrons)

$$T(\omega) = \int_{\partial\Omega_L} \int_{\partial\Omega_L} \int_{\partial\Omega_R} \int_{\partial\Omega_R} \Gamma_L(r_L, r'_L; \omega) G^r(r'_L, r_R; \omega) \\ \times \Gamma_R(r_R, r'_R; \omega) G^{r*}(r'_R, r_L; \omega) dr_L dr'_L dr_R dr'_R,$$

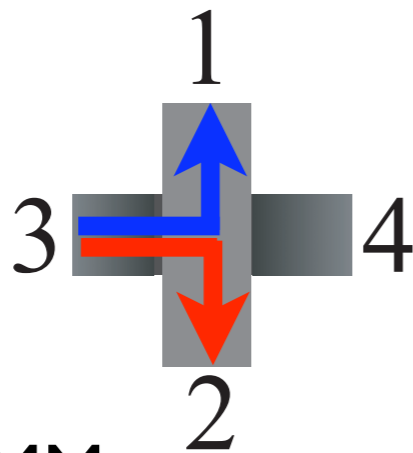
$$I = \int_{-\infty}^{\infty} T(\omega) (f_L(\omega) - f_R(\omega)) d\omega$$

Electron transport calculations with FHI-aims

- Possibility to compare to other results from FHI-aims
- Local basis functions (Important to test that there is enough.)
- Radii of the basis functions are large
- All electron \Rightarrow a lot of basis functions (core states projection)
- 2-4 leads, flexible boundary conditions
- Parallelization: lapack and scalapack.
 - boundary conditions: lapack - over leads
 - center region lapack / scalapack
- Reference potential level is smallest eigenvalue of atoms

Example: Transport properties of junctions

Junction:

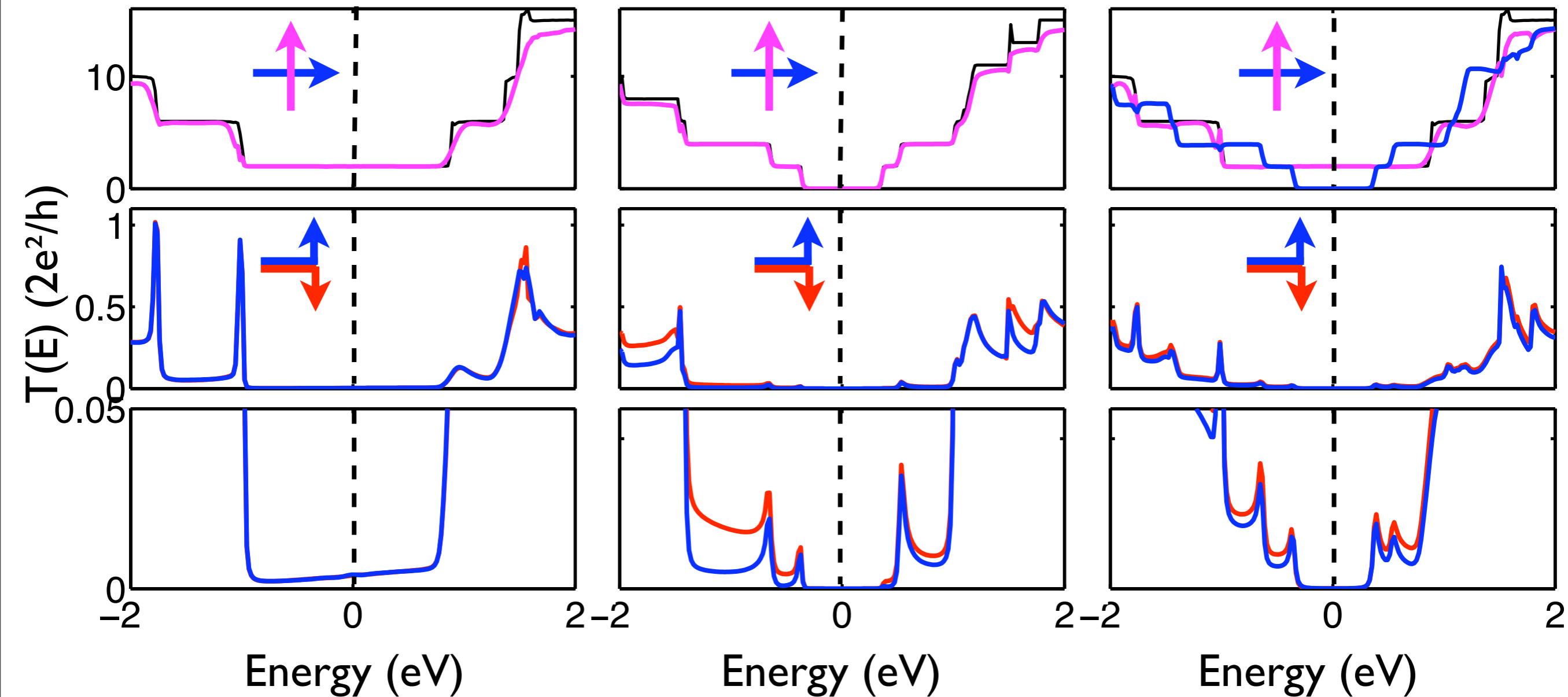


$$G = \frac{2e^2}{\pi} \int_{-\infty}^{\infty} T(E) \left(-\frac{\partial f(E)}{\partial E} \right) dE$$

MM

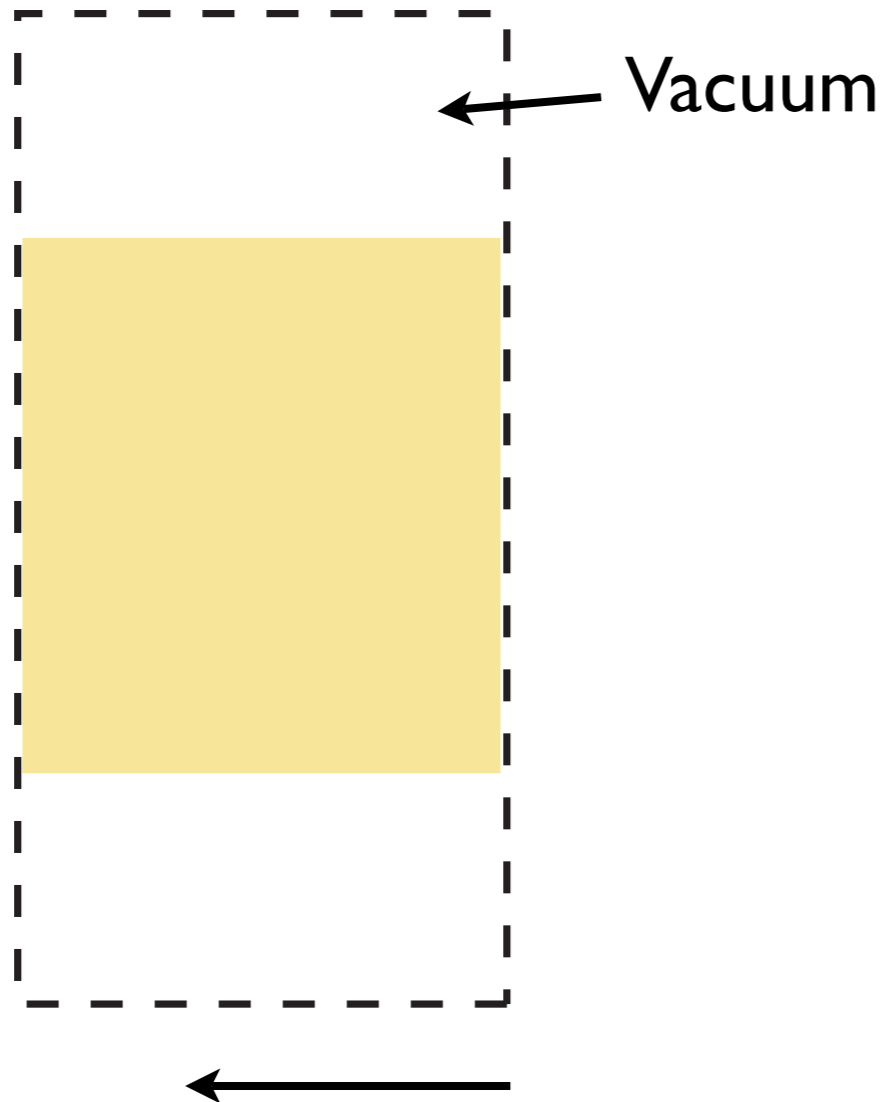
SS

MS



First: Semi-infinite leads

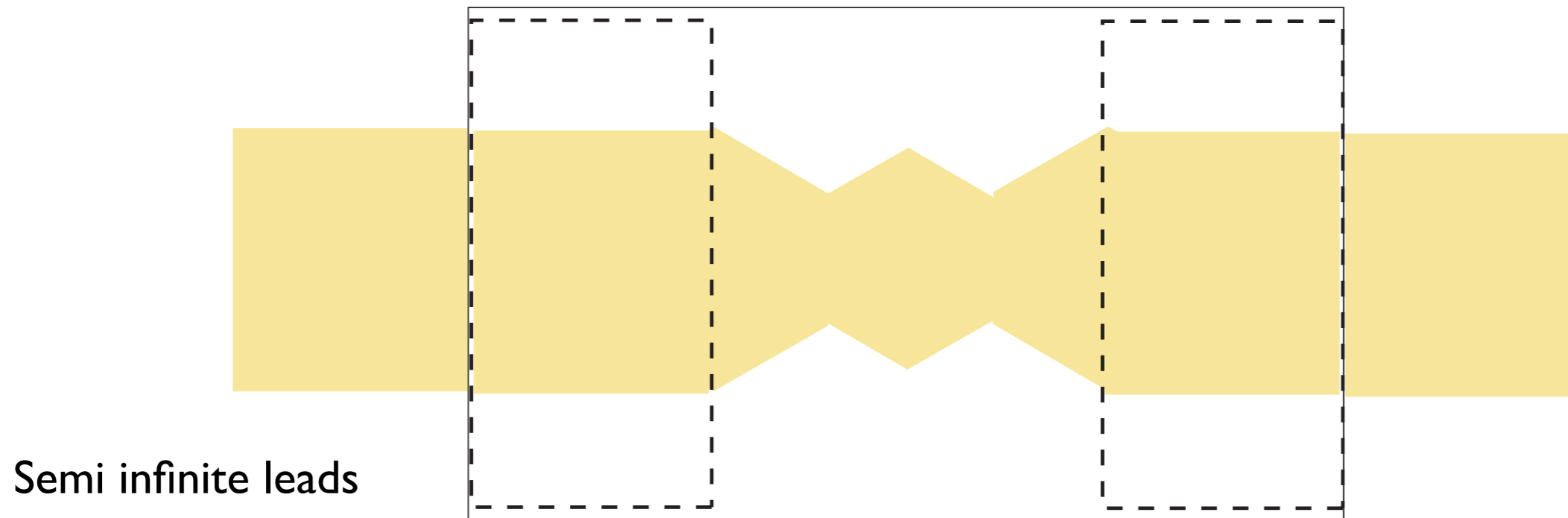
Put in to control.in: `transport lead_calculation`



Lattice vector 3. points
“outside” direction

- Lead calculation with periodic boundary conditions
- One lead calculation for each boundary
- As many k-points as it is needed (as many as in normal calculation) in transport direction
- k-points in perpendicular direction not implemented

Transport in FHI-aims

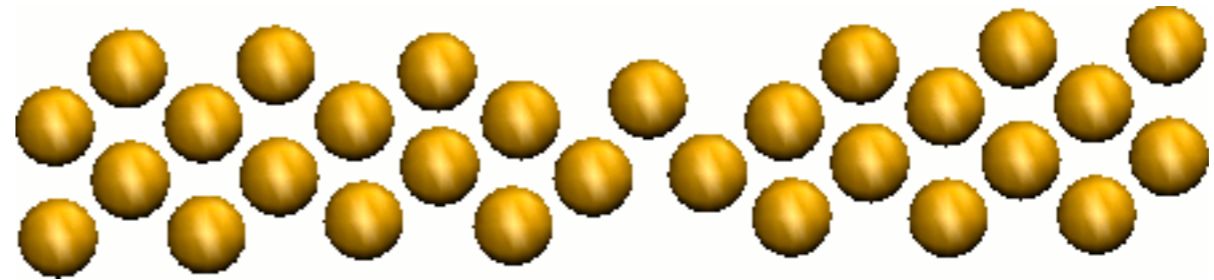


- Actual transport calculation starts with normal periodic boundary calculation.
- Parts of leads need to be in the geometry

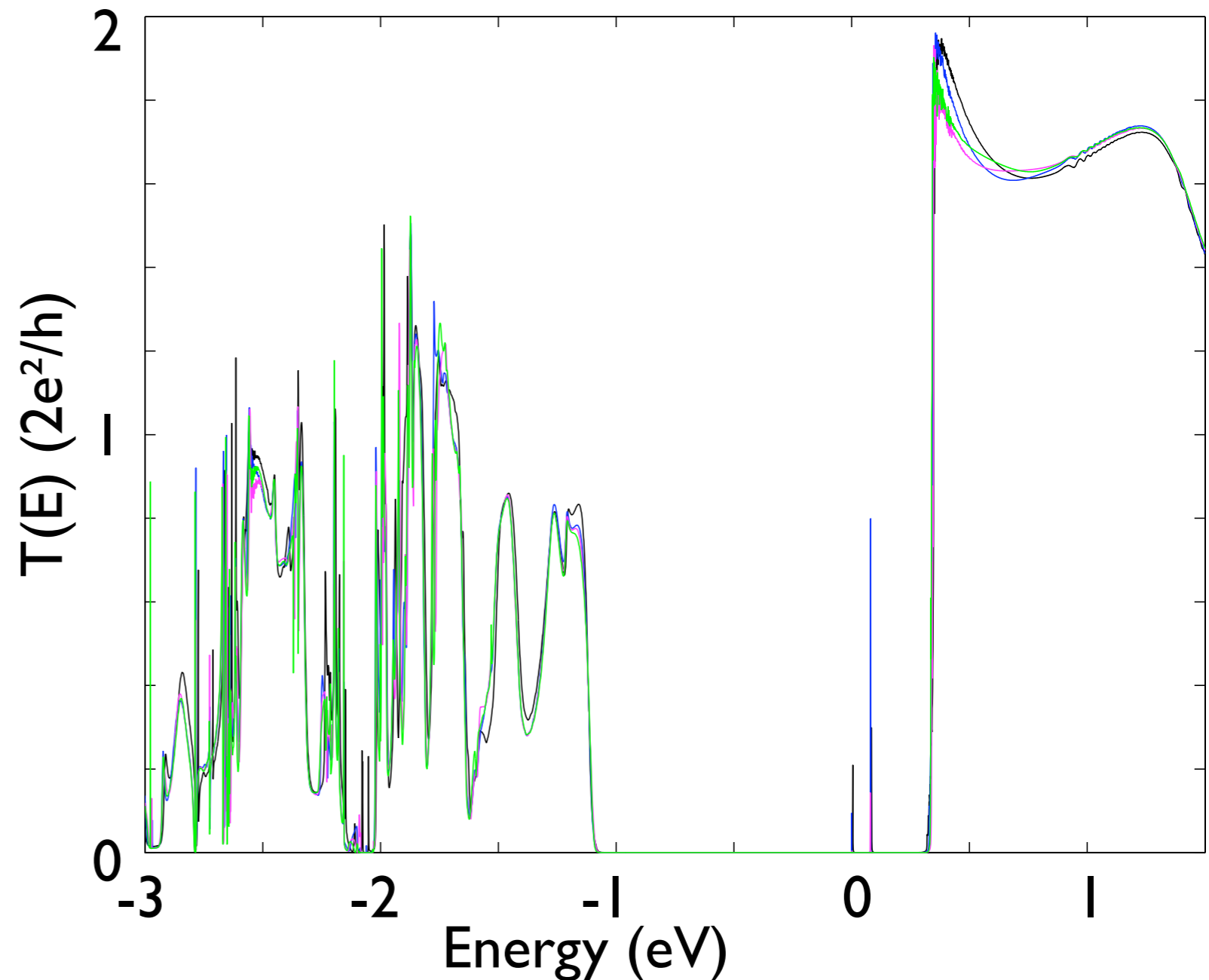
- Computational work depends on
 - number of basis functions
 - how many basis functions are sharing leads and center region
- Boundary conditions are iterated to every energy point, $T(E)$ separately

Au geometry examples

- The part of lead in the geometry needs to be large enough so that the potential is close to leads potential at the boundary.



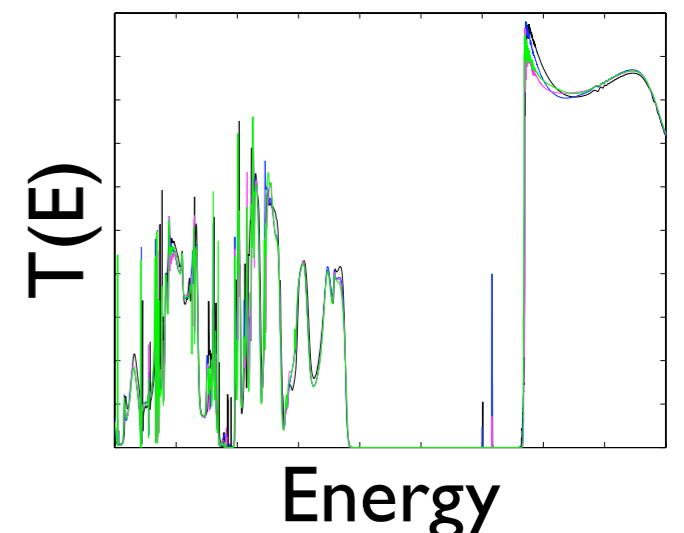
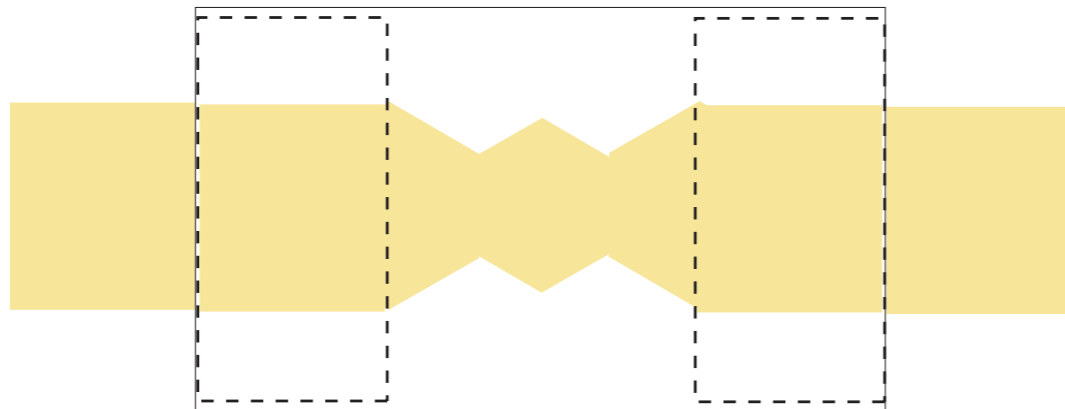
- Au geometries with different lengths:
- 33Å, 49Å, 66Å and 83Å



What to put in control.in in order to get T(E)

```
transport transport_calculation
Results file: transport tunneling_file_name res_file_name
T(E) range: transport energy_range -3.1 1.5 5000
Lead
definitions: transport lead_1 1 lead_1_file_name
transport lead_2 17 lead_2_file_name

Parameters for
the boundary
condition
iterations
transport number_of_boundary_iterations 100
transport boundary_treshold 0.5
transport epsilon_end 0.0001
transport epsilon_start 0.0001
transport boundary_mix 0.5
```



Summary Transport

- Landauer-Büttiker electron transport formula is implemented in FHI-aims.